

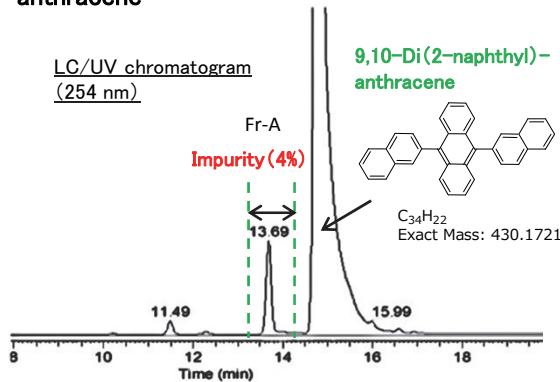
Structural analysis of trace impurity in OLED material by NMR with cryo-cooling probe

It is supposed that the trace impurities (or degradation compounds) in OLED material have a bad influence on the lifetime and emitting properties of OLED. So, it is important to investigate their structures.

In this poster, a trace impurity of OLED material was concentrated by HPLC fractionation and analyzed by NMR with cryo-cooling probe.

HPLC fractionation

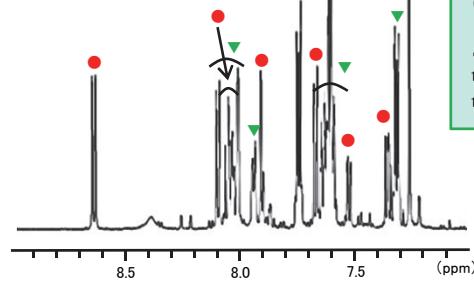
- HPLC fractionation of impurity in 9,10-di(2-naphthyl)-anthracene



1D NMR

¹H NMR spectrum

- :Impurity
- ▼:9,10-Di(2-naphthyl)-anthracene

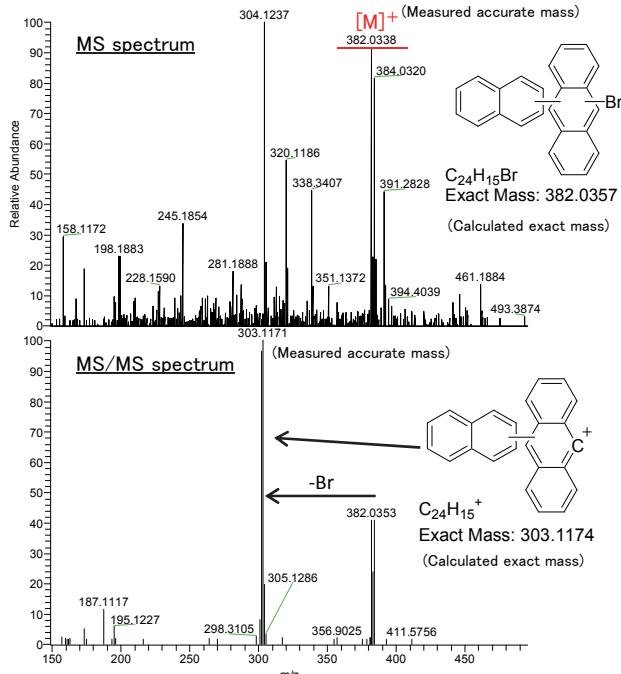


NMR measurements

- 600MHz NMR (+cryo-cooling probe)
- sample weight: 0.6 mg (impurity absolute weight) : 0.1 mg
- number of scan
 - ¹H: 128 times (about 20min)
 - ¹³C: 20000 times (about 16hr)

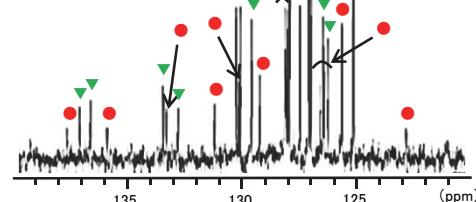
• ¹H NMR and ¹³C NMR spectra show that Fr-A is mixture of 9, 10-Di(2-naphthyl)anthracene(▼) and impurity(●).

LC/MS

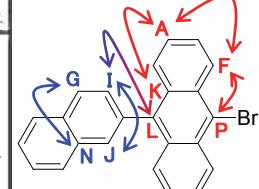
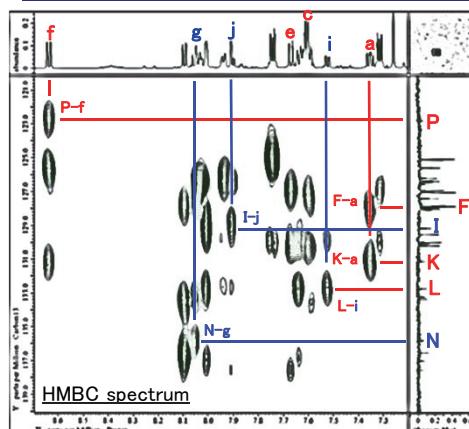


¹³C NMR spectrum

• From characteristic chemical shift, peaks 123 ppm(¹³C) and 8.6 ppm (¹H) are assigned as the halogen adjacent carbon and proton.



2D NMR



Conclusion

- Trace impurity contained in OLED material was concentrated by HPLC fractionation.
- The elemental composition and partial structure were identified by LC/MS measurement.
- Using NMR with cryo-cooling probe, detailed structure of trace impurity was determined.